NSN 5961-01-332-8083

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View Online at https://aerobasegroup.com/nsn/5961-01-332-8083 **Inclosure Material:** Metal **Overall Length:** Between 1.510 inches and 1.550 inches **Overall Height:** Between 0.250 inches and 0.326 inches **Overall Width:** Between 1.005 inches and 1.099 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 drain to source voltage and 1000.0 drain to gate voltage **Current Rating Per Characteristic:** 18.00 amperes off-state current, peak and 2.90 amperes drain current **Power Rating Per Characteristic:** 125.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: